

TEA1993DB1357 synchronous rectifier controller demo boardRev. 1 — 8 April 2016User manual

#### **Document information**

Info	Content
Keywords	TEA1993DB1357, TEA1993TS, flyback converter, Synchronous Rectifier (SR) driver, TSOP-6, high efficiency, power supply, demo board
Abstract	This user manual describes the TEA1993DB1357 demo board. The TEA1993DB1357 demo board can be connected to a flyback converter.
	The TEA1993DB1357 demo board contains a TEA1993TS SR controller in a TSOP-6 package. Additionally, the TEA1993DB1357 demo board contains two possible options to place power MOSFETs. It replaces the secondary rectification part of the flyback converter.



**Revision history** 

Rev	Date	Description
v.1	20160408	first issue

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# 1. Introduction

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Lethal voltage and fire ignition hazard



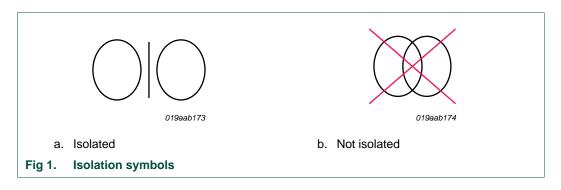
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This document describes the TEA1993DB1357 demo board. A functional description is provided, including instructions about how to connect the board, for the best results and performance. The TEA1993DB1357 demo board contains the secondary part of a single output flyback converter, excluding the output capacitors and the feedback control hardware. To use the TEA1993DB1357 demo board correctly, a flyback converter board in which the demo board can replace the secondary rectifier part is required.

## 2. Safety warning

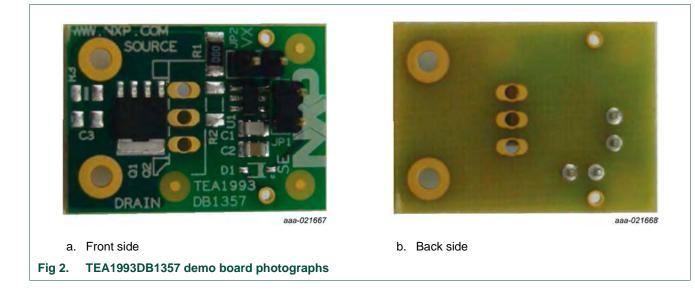
The board application is AC mains voltage powered. Avoid touching the board while it is connected to the mains voltage and when it is in operation. An isolated housing is obligatory when used in uncontrolled, non-laboratory environments. Galvanic isolation from the mains phase using a fixed or variable transformer is always recommended. Figure 1 shows the symbols on how to recognize these devices.



#### TEA1993DB1357 synchronous rectifier controller demo board

# 3. Board photographs

The TEA1993DB1357 demo board incorporates the TEA1993TS in TSOP-6 package and a MOSFET in LFPAK with a typical R<sub>DSon</sub> of 4.8 m $\Omega$ . Figure 2 shows the front side and back side of the TEA1993DB1357 demo board. The TEA1993DB1357 demo board is a single layer board, which includes plated-through vias for external connections and the TO-220 MOSFET.

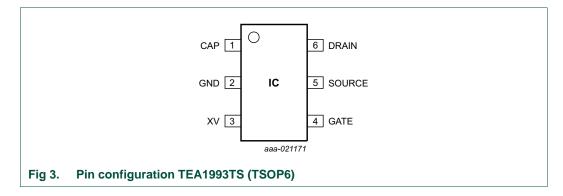


## 4. TEA1993TS SR controller

The TEA1993TS is a dedicated controller IC for synchronous rectification on the secondary side of flyback converters. It incorporates the sensing stage and driver stage for driving the SR MOSFET which rectifies the output of the secondary transformer winding.

The TEA1993TS can generate its own supply voltage or operate with an external applied voltage. The self-supply function is intended for:

- Battery charging applications with a 2 V (USB BC) output voltage
- Applications with high-side rectification without an auxiliary winding
- multiple output voltage applications with or without auxiliary winding



#### 5. TEA1993DB1357 demo board setup

#### 5.1 Connected at low-side SR

The TEA1993DB1357 demo board is incorporated in an existing flyback power supply.

Figure 4 shows the connection of the TEA1993DB1357 demo board to the secondary side of a flyback controller board as low-side SR.

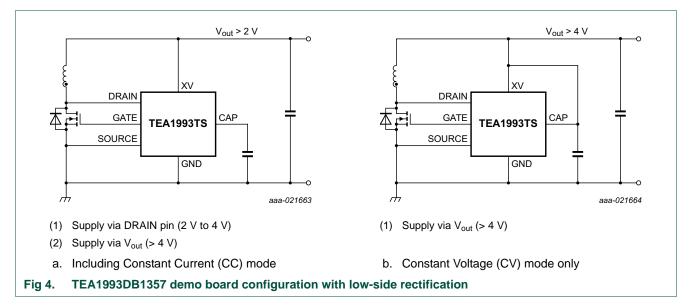


Figure 4(a) shows the configuration for SR low-side applications that include CC mode (e.g. USB BC specification for an operation between 2 V and 5 V). When  $V_{out} \ge 4.7$  V, the TEA1993TS uses the voltage on the XV pin as supply. The resulting voltage on the CAP pin is typically 0.7 V below the voltage on the XV pin. It is used as supply voltage for the gate drive output to the external MOSFET.

When Vout < 4.7 V (CC mode), the TEA1993TS uses the pulsed voltage on the drain input to generate the voltage for the CAP pin. When 0 V < V<sub>out</sub> < 4.7 V, the regulated voltage on the CAP pin is 4.0 V (typical).

Figure 4(b) shows the configuration for SR low-side application for CV mode only. Vout must be  $\geq$  4 V. In this case, the CAP pin can be connected directly to the XV pin. The result of connecting the CAP pin directly to the XV pin is 0.7 V additional gate drive voltage compared to the configuration in Figure 4(a). The additional gate drive voltage drives the external MOSFET to a lower R<sub>DSon</sub> to achieve the best efficiency. The maximum gate drive voltage is limited to 12 V.

Maximum voltage ratings for TEA1993TS pins:

- Pins XV and CAP: 38 V
- Pin DRAIN: 120 V

#### TEA1993DB1357 synchronous rectifier controller demo board

### 5.2 Connected at high-side SR

Figure 5 shows the connection of the TEA1993DB1357 demo board to the secondary side of a flyback controller board as high-side SR.

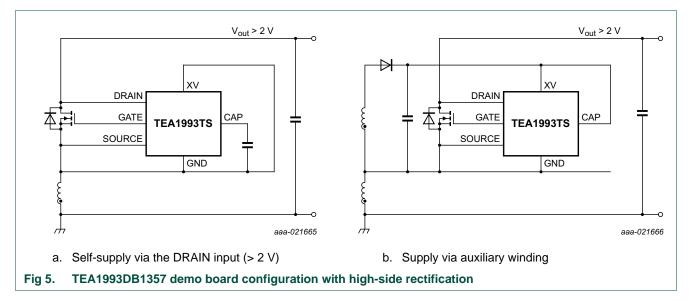


Figure 5(a) shows the configuration for SR high-side applications with self-supply. In this case, the TEA1993TS retrieves its supply from the pulsed voltage on the DRAIN input. The regulator inside the TEA1993TS converts these pulses to an approximately 9 V regulated DC voltage. If the XV pin is connected to the IC ground, the TEA1993TS generates 9 V. This voltage is present on the CAP pin. It is the reference voltage for the gate drive of the external MOSFET.

Figure 5(b) shows the configuration for SR high-side application which is supplied by an additional auxiliary winding. This configuration can deliver the best possible efficiency for high-side application.

If, in a multiple-outputs application, the auxiliary voltage drops below the 4 V for the lower output voltages, the TEA1993TS generates its own supply voltage. It maintains a minimum supply of 4 V on the CAP pin. The auxiliary voltage can then be optimized for the higher output voltages. In this way, maximum efficiency at maximum power is achieved.

Maximum voltage ratings for TEA1993TS pins:

- Pins XV and CAP: 38 V
- Pin DRAIN: 120 V

#### TEA1993DB1357 synchronous rectifier controller demo board

# 6. Schematic

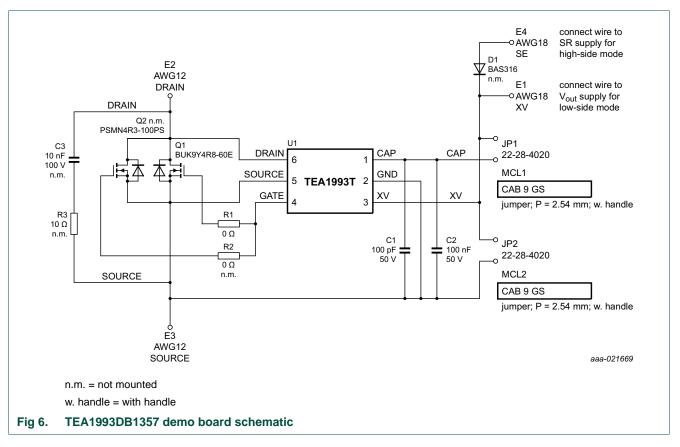


Figure 6 shows the schematic diagram of the TEA1993DB1357 demo board. The board incorporates the TEA1993TS SR controller and a power MOSFET. The TEA1993TS acts as a controlled amplifier. The input is the voltage difference between the DRAIN and the SOURCE pin. The corresponding gate driver signal is the output. The amplifier regulates the source-to-drain voltage difference to 35 mV in the rectification phase.

To facilitate easy layout design for a single-sided board, resistors R1 and R2 are added. They must be between 0  $\Omega$  and 10  $\Omega$ . For the fastest turn-off time, use the lowest value. By default, the LFPAK MOSFET Q1 is mounted with a 0  $\Omega$  gate resistor (R1). It is also possible to mount a TO220 MOSFET Q2 with gate resistor R2. Capacitors C1 and C2 are decoupling capacitors for the V<sub>CC</sub> of the TEA1993TS. Connect these capacitors close to the IC.

To ensure sufficient charge power during the secondary stroke to drive the external MOSFET, a value of 100 nF is used for capacitor C2. To prevent unwanted oscillation of the  $V_{CC}$  supply, capacitor C1 is added. A provision is made for snubber R3/C3. The components are not mounted. However, if high-voltage spikes occur on the drain-source connections of the MOSFETs, they can be added. To facilitate optimal configurations for either the low-side or the high-side connection, jumpers JP1 and JP2 are added (see the diagrams in Section 5).

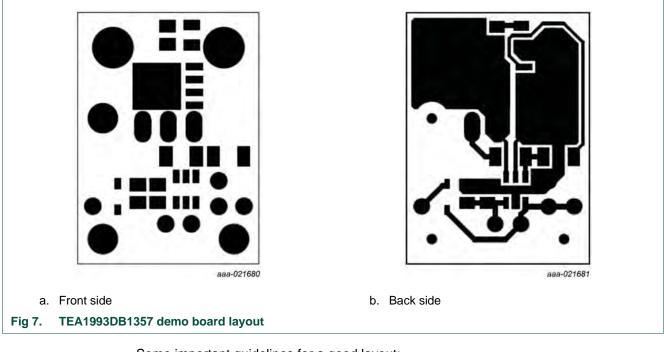
# 7. Bill Of Materials (BOM)

#### Table 1. TEA1993DB1357 demo board BOM

Reference	Description and values	Part number	Manufacturer
C1; C2	capacitor; 100 pF; 50 V; 0805	-	-
C3	capacitor; not mounted; 10 nF; 100 V; 0805	-	-
D1	diode; not mounted; SOD323	BAS316	NXP Semiconductors
JP1; JP2	header; straight; 1 × 2-way	22-28-4020	Molex
MCL1; MCL2	jumper; with handle; P = 2.54 mm	CAB 9 GS	Fischer
R1	resistor; 0 Ω; 1206	-	-
R2	resistor; not mounted; 0 $\Omega$ ; 1206	-	-
R3	resistor; not mounted; 10 $\Omega$ ; 0805	-	-
Q1	MOSFET; LFPAK	BUK9Y4R8-60E	NXP Semiconductors
U1	SR controller; TEA1993TS	TSOP-6	NXP Semiconductors

TEA1993DB1357 synchronous rectifier controller demo board

## 8. Layout



Some important guidelines for a good layout:

- Keep the trace from the DRAIN pin to the MOSFET drain as short as possible
- Keep the trace from the SOURCE pin to the MOSFET source as short as possible
- Keep the area of the loop from the DRAIN pin, to the MOSFET drain, to the MOSFET source, and to the SOURCE pin as small as possible. Make sure that the overlap of this loop over the power drain track or the power source track is as small as possible. Take care that the two loops do not cross each other.
- Keep the track from the GATE pin to the gate of the MOSFET as short as possible
- Use separate clean tracks for the XV and the GND pins. If possible, use a small ground plane underneath the IC, which improves the heat dispersion.

# 9. NXP Semiconductors power MOSFETs

#### Q<sub>G(tot)</sub> Type number Package name V<sub>DS(max)</sub> (V) R<sub>DSon(max)</sub> at I<sub>D(max)</sub> (A) Q<sub>GD</sub> V<sub>GS</sub> = 10 V (typical; nC) (typical; nC) (mΩ) PSMN2R4-30MLD LFPAK33 30 2.4 70 5.6 16 PSMN1R0-30YLD LFPAK56 30 1.02 100 11 38 PSMN1R0-40YLD LFPAK56 40 1.1 17 100 59 PSMN1R4-40YLD LFPAK56 40 1.4 100 13 45 PSMN1R5-40ES 12PAK 40 1.6 120 32 136 PSMN1R5-40PS TO-220AB 40 32 1.6 150 136 PSMN1R6-40YLC LFPAK56 40 1.55 100 15.3 59 PSMN1R8-40YLC LFPAK56 40 100 10.9 1.8 45 PSMN1R9-40PL TO-220AB 40 1.7 40.9 230 150 PSMN2R1-40PL TO-220AB 40 2.2 29.6 150 168.9 PSMN2R2-40PS TO-220AB 40 100 25 2.1 110 PSMN2R6-40YS 2.8 LFPAK56 40 14 63 100 PSMN2R8-40PS TO-220AB 40 17 2.8 100 71 PSMN3R3-40YS LFPAK56 40 100 3.3 11.2 49 PSMN4R0-40YS LFPAK56 40 4.2 7 100 38 PSMN4R5-40PS TO-220AB 40 4.6 8.8 100 35 PSMN5R8-40YS LEPAK56 40 5.7 90 7.8 28.8 PSMN8R0-40PS TO-220AB 40 7.6 77 3.8 17 PSMN8R3-40YS LFPAK56 40 8.6 70 4.5 20 **I2PAK** 60 2.2 32 PSMN2R0-60ES 120 137 PSMN2R0-60PS TO-220AB 60 2.2 120 32 137 PSMN2R5-60PL TO-220AB 60 2.6 150 41.2 223 TO-220AB PSMN2R6-60PS 60 2.6 150 43.7 140 PSMN3R0-60ES **I2PAK** 60 3 100 28 130 PSMN3R0-60PS TO-220AB 60 3 100 28 130 PSMN3R3-60PL TO-220AB 60 3.4 130 31 175 PSMN3R9-60PS TO-220AB 60 3.9 130 33 103 PSMN4R2-60PL TO-220AB 3.9 130 27 151 60 PSMN4R6-60PS TO-220AB 60 4.6 100 14.8 70.8 PSMN5R5-60YS LFPAK56 60 5.2 100 11.2 56 PSMN7R0-60YS 6.4 LFPAK56 60 89 9.6 45 PSMN7R6-60PS TO-220AB 60 7.8 92 10.6 38.7 PSMN8R5-60YS LFPAK56 60 7.7 8 76 39 27 PSMN3R3-80ES **I2PAK** 60 3.3 120 139 PSMN3R3-80PS TO-220AB 60 3.3 120 27 139 PSMN3R5-80ES **I2PAK** 80 3.5 120 27 139 TO-220AB PSMN3R5-80PS 80 3.5 120 27 139

#### Table 2. Extract from the NXP Semiconductors power MOSFET selection guide

## **NXP Semiconductors**

# UM10963

#### TEA1993DB1357 synchronous rectifier controller demo board

Type number	Package name	V <sub>DS(max)</sub> (V)	$R_{DSon(max)}$ at V <sub>GS</sub> = 10 V (m $\Omega$ )	I <sub>D(max)</sub> (A)	Q <sub>GD</sub> (typical; nC)	Q <sub>G(tot)</sub> (typical; nC)
PSMN4R3-80ES	I2PAK	80	4.3	120	28	111
PSMN4R3-80PS	TO-220AB	80	4.3	120	28.4	111
PSMN4R4-80PS	TO-220AB	80	4.1	100	25	112
PSMN5R0-80PS	TO-220AB	80	4.7	100	21	87
PSMN6R5-80PS	TO-220AB	80	6.9	100	16	71
PSMN8R2-80YS	LFPAK56	80	8.5	82	12	55
PSMN8R7-80PS	TO-220AB	80	8.7	90	11	52
PSMN4R3-100ES	I2PAK	100	4.3	120	49	170
PSMN4R3-100PS	TO-220AB	100	4.3	120	49	170
PSMN5R0-100ES	I2PAK	100	5	120	49	170
PSMN5R0-100PS	TO-220AB	100	5	120	49	170
PSMN5R6-100PS	TO-220AB	100	5.6	100	43	141
PSMN7R0-100ES	I2PAK	100	6.8	100	36	125
PSMN7R0-100PS	TO-220AB	100	6.8	100	36	125
PSMN8R5-100ES	I2PAK	100	8.5	100	33	111
PSMN8R5-100PS	TO-220AB	100	8.5	100	33	111
PSMN6R3-120ES	I2PAK	120	6.7	70	61.9	207.1
PSMN6R3-120PS	TO-220AB	120	6.7	70	61.9	207.1
PSMN7R8-120ES	I2PAK	120	7.9	70	50.5	167
PSMN7R8-120PS	TO-220AB	120	7.9	70	50.5	167

#### Table 2. Extract from the NXP Semiconductors power MOSFET selection guide ...continued

# **10. Abbreviations**

Table 3. Abbreviations		
Acronym	Description	
SR	Synchronous Rectifier	
MOSFET	Metal-Oxide-Semiconductor Field-Effect Transistor	
CC	Constant Current	
CV	Constant Voltage	

# 11. References

[1] **TEA1993TS data sheet** — GreenChip synchronous rectifier controller; 2015, NXP Semiconductors

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User manual

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# UM10963

TEA1993DB1357 synchronous rectifier controller demo board

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